

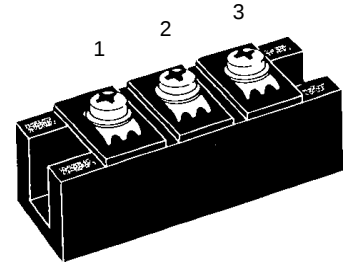
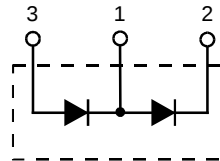
High Power Diode Modules

$$I_{FRMS} = 2 \times 300 \text{ A}$$

$$I_{FAVM} = 2 \times 190 \text{ A}$$

$$V_{RRM} = 800-1800 \text{ V}$$

V_{RSM} V V	V_{RRM} V V	Type
900	800	MDD 172-08N1
1300	1200	MDD 172-12N1
1500	1400	MDD 172-14N1
1700	1600	MDD 172-16N1
1900	1800	MDD 172-18N1



Symbol	Test Conditions	Maximum Ratings
I_{FRMS}	$T_{VJ} = T_{VJM}$	300 A
I_{FAVM}	$T_C = 100^\circ\text{C}; 180^\circ \text{ sine}$	190 A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}; V_R = 0$	6600 A
	$t = 10 \text{ ms (50 Hz), sine}$	7290 A
	$t = 8.3 \text{ ms (60 Hz), sine}$	5600 A
	$T_{VJ} = T_{VJM}; V_R = 0$	6200 A
	$t = 10 \text{ ms (50 Hz), sine}$	157 000 A ² s
	$t = 8.3 \text{ ms (60 Hz), sine}$	160 000 A ² s
$\int i^2 dt$	$T_{VJ} = 45^\circ\text{C}; V_R = 0$	218 000 A ² s
	$t = 10 \text{ ms (50 Hz), sine}$	221 000 A ² s
	$t = 8.3 \text{ ms (60 Hz), sine}$	157 000 A ² s
	$T_{VJ} = T_{VJM}; V_R = 0$	160 000 A ² s
T_{VJ}		-40...+150 °C
T_{VJM}		150 °C
T_{stg}		-40...+125 °C
V_{ISOL}	50/60 Hz, RMS $t = 1 \text{ min}$	3000 V~
	$I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	3600 V~
M_d	Mounting torque (M6)	2.25-2.75/20-25 Nm/lb.in.
	Terminal connection torque (M6)	4.5-5.5/40-48 Nm/lb.in.
Weight	Typical including screws	120 g

Features

- International standard package
- Direct copper bonded Al_2O_3 -ceramic base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered, E 72873

Applications

- Supplies for DC power equipment
- DC supply for PWM inverter
- Field supply for DC motors
- Battery DC power supplies

Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

Symbol	Test Conditions	Characteristic Values
I_R	$T_{VJ} = T_{VJM}; V_R = V_{RRM}$	20 mA
V_F	$I_F = 300 \text{ A}; T_{VJ} = 25^\circ\text{C}$	1.15 V
V_{T0}	For power-loss calculations only	0.8 V
r_T	$T_{VJ} = T_{VJM}$	0.8 mΩ
Q_S	$T_{VJ} = 125^\circ\text{C}; I_F = 300 \text{ A}, -di/dt = 50 \text{ A}/\mu\text{s}$	550 μC
I_{RM}		235 A
R_{thJC}	per diode; DC current	0.21 K/W
	per module	0.105 K/W
R_{thJK}	per diode; DC current	0.31 K/W
	per module	0.155 K/W
d_s	Creepage distance on surface	12.7 mm
d_a	Strike distance through air	9.6 mm
a	Maximum allowable acceleration	50 m/s ²

Data according to IEC 60747 and refer to a single diode unless otherwise stated.
IXYS reserves the right to change limits, test conditions and dimensions

Dimensions in mm (1 mm = 0.0394")

